

### Ultra minimum package size, SSOP (1 Form A) 4-pin type. Lower output capacitance and on resistance. (C×R5)

#### 4.45 .175 1.80 .071

mm inch



**FEATURES 1. Reduced package size** Lower surface has been reduced 60% and mounting space 40% compared to

and mounting space 40% compared to conventional 4-pin SOP type.

2. Lower output capacitance and onresistance

Output capacitance (C): 1.0pF (typ.) ON resistance (R): 5.5Ω (typ.)

3. Mounting space has been reduced and output signals have been improved by using new flat lead terminals.



**4. High speed switching** Turn on time: 0.02ms Turn off time: 0.02ms

# RF PhotoMOS (AQY221N3V)

### **TYPICAL APPLICATIONS**

Measuring and testing equipment

- 1. Test equipment IC tester, Liquid crystal driver tester, semiconductor performance tester
- 2. Board tester Bare board tester, In-circuit tester, function tester
- 3. Medical equipment Ultrasonic wave diagnostic machine
- 4. Multi-point recorder Warping, thermo couple

### TYPES

Circuit arrangement	Туре	Output rating*		Tape and reel	Packing quantity	
		Load voltage	Load current	Picked from the 1/4-pin side	Picked from the 2/3-pin side	in tape and reel
1 Form A	AC/DC type	25 V	150 mA	AQY221N3VY	AQY221N3VW	3,500 pcs.

\* Indicate the peak AC and DC values.

Notes: (1) Tape package is the standard packing style.

(2) For space reasons, the initial letters of the product number "AQY", the package type indicator "Y" and "W" are omitted from the seal. (Ex. the label for product number AQY221N3V is 221N3)

# RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY221N3V	Remarks	
Input	LED forward current	lF	50mA		
	LED reverse voltage	Vr	5V		
	Peak forward current	IFP	1A	f=100 Hz, Duty factor=0.1%	
	Power dissipation	Pin	75mW		
Output	Load voltage (peak AC)	VL	25V		
	Continuous load current (peak AC)	IL I	0.15A	Peak AC,DC	
	Peak load current	Ipeak	0.4A	100 ms (1 shot), V∟= DC	
	Power dissipation	Pout	250mW		
Total power dissipation		Ρτ	300mW		
I/O isolation voltage		Viso	1,500V AC		
Temperature limits	Operating	Topr	-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures	
	Storage	Tstg	-40°C to +100°C -40°F to +212°F		

# RF PhotoMOS (AQY221N3V)

#### 2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item				Symbol	AQY221N3V	Condition
Input	LED operate current		Typical		1.0 mA	I∟ = 80 mA
			Maximum	Fon	3.0 mA	
	LED turn off current		Minimum		0.2 mA	I∟ = 80 mA
			Typical	Foff	0.9 mA	
	LED dropout voltage		Typical		1.35 V (1.14 V at I⊧ = 5 mA)	IF = 50 mA
			Maximum	VF	1.5 V	
Output	On resistance		Typical		5.5Ω	I⊧ = 5 mA I∟ = 80 mA Within 1 s on time
			Maximum	Ron	7.5Ω	
	Output capacitance		Typical	0	1.0 pF	I <sub>F</sub> = 0 mA V <sub>B</sub> = 0 V f = 1 MHz
			Maximum	Cout	1.5 pF	
	Off state leakage current		Typical		0.01 nA	I⊧ = 0 mA V∟ = Max.
			Maximum	Leak	10 nA	
Transfer characteristics	Switching speed	Turn on time*	Typical	<b>–</b>	0.02 ms	I⊧ = 5 mA V∟ = 10 V R∟ = 125Ω
			Maximum	Ton	0.2 ms	
		Turn off time*	Typical	т	0.02 ms	I⊧ = 5 mA VL = 10 V RL = 125Ω
			Maximum	Toff	0.2 ms	
	I/O capacitance		Typical	0	0.8 pF	f = 1 MHz V <sub>B</sub> = 0 V
			Maximum	Ciso	1.5 pF	
	Initial I/O isolation resistance		Minimum	Riso	1,000ΜΩ	500V DC

Note: Recommendable LED forward current  $I_F$  = 5 mA.

#### \*Turn on/Turn off time



### **REFERENCE DATA**

1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



2. Load current vs. Load voltage characteristics Ambient temperature: 25°C  $77^\circ\text{F}$ 



# 3. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4 LED current: 5 mA; Load voltage: 10V (DC); Load current: 80mA (DC)



All Rights Reserved © COPYRIGHT Matsushita Electric Works, Ltd.

# 4. Turn on time vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4 LED current: 5 mA; Load voltage: 10V (DC); Continuous load current: 80mA (DC)



7. LED turn off current vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4 Load voltage: 10V (DC);



10. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4 Ambient temperature:  $25^{\circ}C$   $77^{\circ}F$ 



13. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4 Frequency: 1 MHz, 30m Vrms; Ambient temperature: 25°C 77°F



5. Turn off time vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4 LED current: 5 mA; Load voltage: 10V (DC); Continuous load current: 80mA (DC)



8. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



11. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4 Load voltage: 10V (DC); Continuous load current: 80mA (DC); Ambient temperature: 25°C 77°F



14. Isolation vs. frequency characteristics  $(50\Omega \text{ impedance})$ 

Measured portion: between terminals 3 and 4 Ambient temperature: 25°C 77°F



6. LED operate current vs. ambient temperature characteristics Measured portion: between terminals 3 and 4 Load voltage: 10V (DC); Continuous load current: 80mA (DC)



 Current vs. voltage characteristics of output at MOS portion
Measured portion: between terminals 3 and 4
Ambient temperature: 25°C 77°F



12. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4 Load voltage: 10V (DC); Continuous load current: 80mA (DC); Ambient temperature: 25°C 77°F



15. Insertion loss vs. frequency characteristics (50  $\!\Omega$  impedance)

Measured portion: between terminals 3 and 4 Ambient temperature: 25°C 77°F



All Rights Reserved © COPYRIGHT Matsushita Electric Works, Ltd.

# RF PhotoMOS (AQY221N3V)

# RF PhotoMOS (AQY221N3V)

16. On resistance distribution

Measured portion: between terminals 3 and 4 Continuous load current: 80mA (DC) Ambient temperature: 25°C 77°F



bient temperature:  $25^{\circ}C$  77°F

- LED operate current, mA

17. Turn on time distribution Load voltage: 10V (DC) Continuous load current: 80mA (DC) Ambient temperature: 25°C 77°F



18. Turn off time distribution Load voltage: 10V (DC) Continuous load current: 80mA (DC) Ambient temperature: 25°C 77°F

